

Dual high-speed switching diode Rev. 5 — 6 March 2012

Product data sheet

Product profile

1.1 General description

Dual high-speed switching diode, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- High switching speed: $t_{rr} \le 4$ ns
- Repetitive peak reverse voltage: $V_{RRM} \leq 85 \ V$
- Reverse voltage: V_R ≤ 80 V
- AEC-Q101 qualified

- Low capacitance: C_d ≤ 1.5 pF
- Repetitive peak forward current: $I_{FRM} \le 500 \text{ mA}$
- Very small SMD plastic package

1.3 Applications

- High-speed switching
- General-purpose switching

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
I _F	forward current		<u>[1]</u>			
			[2] _	-	250	mA
			[3] _	-	160	mA
I_R	reverse current	$V_{R} = 80 \text{ V}$	-	-	0.5	μΑ
V_R	reverse voltage		-	-	80	V
t _{rr}	reverse recovery time		<u>[4]</u> _	-	4	ns

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

- [2] Single diode loaded.
- [3] Double diode loaded.
- [4] When switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100$ Ω ; measured at $I_R = 1$ mA.



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2. Pinning information

Table 2. Pinning

Table 2.	Filling		
Pin	Description	Simplified outline	Graphic symbol
1	anode (diode 1)		
2	anode (diode 2)	3	3
3	common cathode	1 2	1 2 006aab034

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
1PS301	SC-70	plastic surface-mounted package; 3 leads	SOT323

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
1PS301	B*3

^{[1] * =} placeholder for manufacturing site code

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V_{RRM}	repetitive peak reverse voltage		-	85	V
V _R	reverse voltage		-	80	V
I _F	forward current		<u>[1]</u>		
			[2] -	250	mA
			<u>[3]</u> _	160	mA
I _{FRM}	repetitive peak forward current	$t_p \leq 0.5~\mu\text{s}; \\ \delta \leq 0.25$	-	500	mA
I _{FSM}	non-repetitive peak forward	square wave	<u>[4]</u>		
	current	t _p = 1 μs	-	4	Α
		t _p = 1 s	-	0.5	Α

1PS30

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 Table 5.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	<u>[1]</u> _	300	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device						
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1]</u> _	-	415	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		-	-	200	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

7. Characteristics

Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode	e					
V _F forward voltage	forward voltage	I _F = 1 mA	-	610	-	mV
	I _F = 10 mA	-	740	-	mV	
		I _F = 50 mA	-	-	1.0	V
		I _F = 100 mA	-	-	1.2	V
I _R reverse current	reverse current	V _R = 25 V	-	-	30	nA
	V _R = 80 V	-	-	0.5	μΑ	
		V _R = 25 V; T _j = 150 °C	-	-	30	μΑ
		$V_R = 80 \text{ V}; T_j = 150 ^{\circ}\text{C}$	-	-	100	μΑ
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	-	1.5	pF
t _{rr}	reverse recovery time		<u>[1]</u> _	-	4	ns
V_{FR}	forward recovery voltage		[2] _	-	1.75	V

^[1] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.

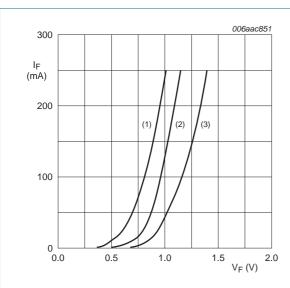
^[2] Single diode loaded.

^[3] Double diode loaded.

^[4] $T_j = 25$ °C before surge.

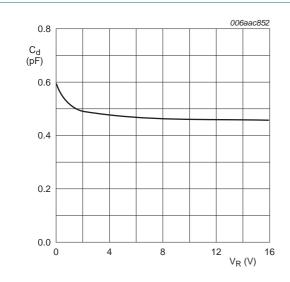
^[2] When switched from $I_F = 10$ mA; $t_r = 20$ ns.

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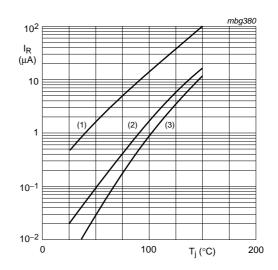
- (1) $T_i = 150 \,^{\circ}\text{C}$; typical values
- (2) $T_i = 25 \,^{\circ}\text{C}$; typical values
- (3) $T_i = 25 \, ^{\circ}C$; maximum values

Fig 1. Forward current as a function of forward voltage



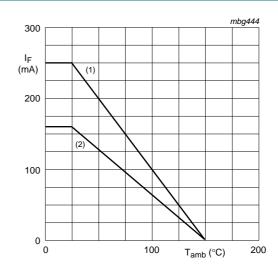
 $f = 1 \text{ MHz}; T_{amb} = 25 ^{\circ}\text{C}$

Fig 3. Diode capacitance as a function of reverse voltage; typical values



- (1) $V_R = 80 \text{ V}$; maximum values
- (2) V_R = 80 V; typical values
- (3) $V_R = 25 V$; typical values

Fig 2. Reverse current as a function of junction temperature



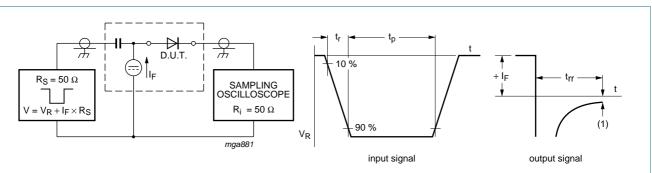
FR4 PCB, standard footprint

- (1) single diode loaded
- (2) double diode loaded

Fig 4. Forward current as a function of ambient temperature; derating curves

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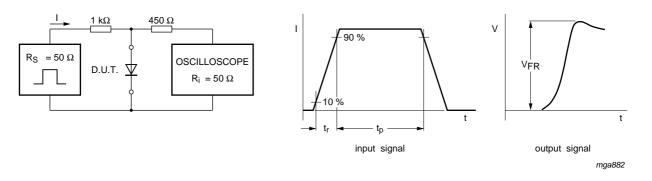
8. Test information



(1) $I_R = 1 \text{ mA}$

Input signal: reverse pulse rise time t_r = 0.6 ns; reverse voltage pulse duration t_p = 100 ns; duty cycle δ = 0.05 Oscilloscope: rise time t_r = 0.35 ns

Fig 5. Reverse recovery time test circuit and waveforms



Input signal: forward pulse rise time t_r = 20 ns; forward current pulse duration $t_p \ge 100$ ns; duty cycle $\delta \le 0.005$

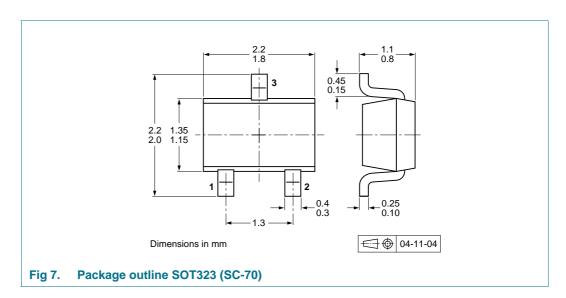
Fig 6. Forward recovery voltage test circuit and waveforms

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 8. Packing methods

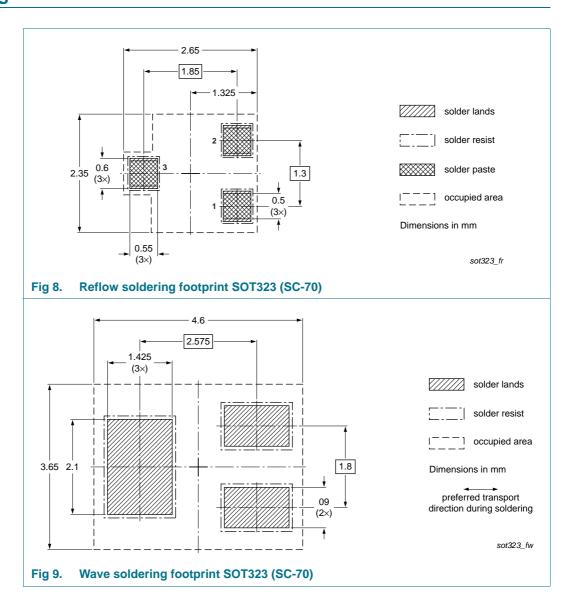
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing q	uantity
			3000	10000
1PS301	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135

^[1] For further information and the availability of packing methods, see Section 14.

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11. Soldering



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12. Revision history

Table 9. Revision history

	•					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
1PS301 v.5	20120306	Product data sheet	-	1PS301 v.4		
Modifications:		of this document has been if NXP Semiconductors.	redesigned to comply v	with the new identity		
	 Legal texts have been adapted to the new company name where appropriate. 					
	Section 1.1	"General description": amer	nded			
	 Table 1 "Qu 	ick reference data": added				
	 Section 4 "N 	Marking": updated				
	Section 8 "Test information": added					
	Figure 7: superseded by minimized package outline drawing					
	Section 10 "Packing information": added					
	Section 11 "Soldering": added					
	 Section 13 * 	Legal information": updated	I			
1PS301 v.4	19990506	Product data sheet	-	1PS301 v.3		
1PS301 v.3	19961004	Product specification	-	1PS301 v.2		
1PS301 v.2	19960903	Product specification	-	1PS301 v.1		
1PS301 v.1	19960403	Product specification	-	-		

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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